

Continental Device India Limited

An ISO/TS 16949, ISO 9001 and ISO 14001 Certified Company



2N1711

NPN SILICON PLANAR TRANSISTOR



TO-39 Metal Can Package

General Purpose Transistor

ABSOLUTE MAXIMUM RATINGS

DESCRIPTION	SYMBOL	VALUE	UNIT
Collector Emitter Voltage, R _{BE} ≤ 10 W	V_{CER}	50	V
Collector Base Voltage	V_{CBO}	75	V
Emitter Base Voltage	V_{EBO}	7.0	V
Power Dissipation at T _a =25°C	P_{D}	800	mW
Derate Above 25°C		4.57	mW/ ºC
Power Dissipation at T _c =25°C	P_{D}	3.0	W
Derate Above 25°C		17.15	mW/ °C
Operating and Storage Junction	T _i , T _{stg}	- 65 to +200	°C
Temperature Range	'j, 'stg	33 13 1200	

ELECTRICAL CHARACTERISTICS (T_a=25°C unless specified otherwise)

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DESCRIPTION	SYMBOL	TEST CONDITION	TEST CONDITION MIN TYP		MAX	UNIT		
Collector Emitter Voltage	V_{CER}	$I_C=1$ mA, $R_{BE} \leq 10 \Omega$	50			V		
Collector Base Voltage	V_{CBO}	$I_{C}=100\mu A, I_{E}=0$	75			V		
Emitter Base Voltage	V_{EBO}	$I_{E}=100\mu A, I_{C}=0$	7.0			V		
Collector Cut Off Current	I _{CBO}	$V_{CB}=60V, I_{E}=0$			10	nA		
		V _{CB} =60V, I _E =0, T _a =150°C			10	μΑ		
Emitter Cut Off Current	I _{EBO}	$V_{EB}=5V$, $I_{C}=0$			5.0	nA		
DC Current Gain	h _{FE}	I _C =0.01mA, V _{CE} =10V	20					
		$I_C=0.1$ mA, $V_{CE}=10$ V	35					
		I _C =10mA, V _{CE} =10V	75					
		I _C =10mA, V _{CE} =10V, T _a = -55°C	35					
		I _C =150mA, V _{CE} =10V	100		300			
		I _C =500mA, V _{CE} =10V	40					
Collector Emitter Saturation Voltage	*V _{CE (sat)}	I _C =150mA, I _B =15mA			0.5	V		
Base Emitter Saturation Voltage	*V _{BE (sat)}	I _C =150mA, I _B =15mA			1.3	V		

SMALL SIGNAL CHARACTERISTICS

DESCRIPTION	SYMBOL	TEST CONDITION	MIN	TYP	MAX	UNIT
Transition Frequency	f _T	I_C =50mA, V_{CE} =10V, f=20MHz	70			MHz
Output Capacitance	C_{ob}	V_{CB} =10V, I_{E} =0, f=100KHz			25	pF
Input Capacitance	C_{ib}	V_{EB} =0.5V, I_{C} =0, f=100KHz			80	pF
Input Impedance	h _{ib}	$I_C=1$ mA, $V_{CB}=5$ V, $f=1$ KHz	24		34	Ω
		$I_C=5$ mA, $V_{CB}=10$ V, $f=1$ KHz	4.0		8.0	Ω
Voltage Feedback Ratio	h _{rb}	$I_C=1$ mA, $V_{CB}=5$ V, $f=1$ KHz			5.0	x10 ⁻⁴
		$I_C=5$ mA, $V_{CB}=10$ V, $f=1$ KHz			5.0	x10 ⁻⁴
Small Signal Current Gain	h _{fe}	$I_C=1$ mA, $V_{CB}=5$ V, $f=1$ KHz	50		200	
		$I_C=5$ mA, $V_{CB}=10$ V, $f=1$ KHz	70		300	

^{*}Pulse Test: Pulse Width < 300ms, Duty Cycle < 2%



TO-39 Metal Can Package

ELECTRICAL CHARACTERISTICS (T_a=25°C unless specified otherwise)

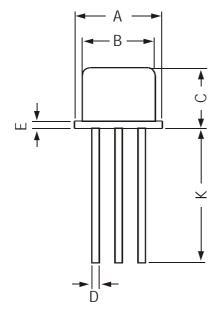
SMALL SIGNAL CHARACTERISTICS

DESCRIPTION	SYMBOL	YMBOL TEST CONDITION		TYP	MAX	UNIT
Output Admittance	h _{ob}	h_{ob} $I_C=1mA$, $V_{CB}=5V$, $f=1KHz$			0.5	μmhos
		$I_C=5$ mA, $V_{CB}=10$ V, $f=1$ KHz	0.05		0.5	μmhos
Noise Figure	NF	I_C =300μA, V_{CE} =10V, f=1KHz			8.0	dB

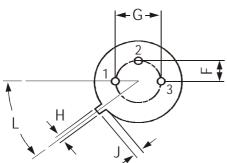
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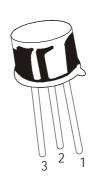
TO-39 Metal Can Package

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DIM	MIN	MAX
Α	8.50	9.39
В	7.74	8.50
С	6.09	6.60
D	0.40	0.53
Ε	_	0.88
F	2.41	2.66
G	4.82	5.33
Н	0.71	0.86
J	0.73	1.02
Κ	12.70	_
L	42 DEG	48 DEG





All dimensions are in mm

PIN CONFIGURATION

- 1. EMITTER
- 2. BASE
- 3. COLLECTOR

Packing Detail

PACKAGE	STANDARD PACK		INNER CARTON BOX		OUTER CARTON BOX		
	Details	Net Weight/Qty	Size	Qty	Size	Qty	Gr Wt
TO-39	500 pcs/polybag	540 gm/500 pcs	3" x 7.5" x 7.5"	20K	17" x 15" x 13.5"	32K	40 kgs

Component Disposal Instructions

- 1. CDIL Semiconductor Devices are RoHS compliant, customers are requested to please dispose as per prevailing Environmental Legislation of their Country.
- 2. In Europe, please dispose as per EU Directive 2002/96/EC on Waste Electrical and Electronic Equipment (WEEE).

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Customer Notes 2N1711

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Disclaimer

The product information and the selection guides facilitate selection of the CDIL's Semiconductor Device(s) best suited for application in your product(s) as per your requirement. It is recommended that you completely review our Data Sheet(s) so as to confirm that the Device(s) meet functionality parameters for your application. The information furnished in the Data Sheet and on the CDIL Web Site/CD are believed to be accurate and reliable. CDIL however, does not assume responsibility for inaccuracies or incomplete information. Furthermore, CDIL does not assume liability whatsoever, arising out of the application or use of any CDIL product; neither does it convey any license under its patent rights nor rights of others. These products are not designed for use in life saving/support appliances or systems. CDIL customers selling these products (either as individual Semiconductor Devices or incorporated in their end products), in any life saving/support appliances or systems or applications do so at their own risk and CDIL will not be responsible for any damages resulting from such sale(s).

CDIL strives for continuous improvement and reserves the right to change the specifications of its products without prior notice.



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